TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

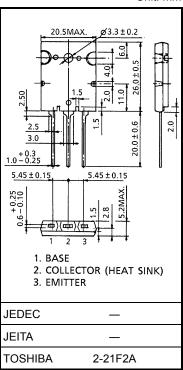
2SC5859

HORIZONTAL DEFLECTION OUTPUT FOR HDTV, DIGITAL TV, PROJECTION TV

- High Voltage : VCBO = 1700 V
- Low Saturation Voltage : VCE (sat) = 3 V (max)
- High Speed $: t_{f(2)} = 0.1 \ \mu s \ (Typ.)$

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V _{CBO}	1700	V	
Collector-Emitter Voltage		V _{CEO}	750	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	23	A	
	Pulse	I _{CP}	46		
Base Current		Ι _Β	11.5	А	
Collector Power Dissipation		P _C	210	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	



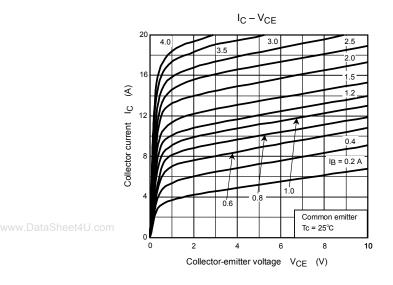
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

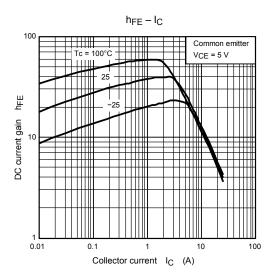
Weight: 9.75 g (typ.)

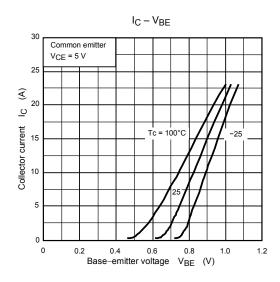
CHARACTERISTIC		SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
Collector Cut-off Current		I _{CBO}	V _{CB} = 1700 V, I _E = 0	—	—	1	mA
Emitter Cut-off Current		I _{EBO}	V _{EB} = 5 V, I _C = 0	_	—	100	μA
Collector – Emitter Breakdown Voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	750	_	_	V
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 2 A	20	—	55	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 8 A	10	_	22	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 18 A	4.5	_	8	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 18 A, I _B = 4.5 A	_	_	3	V
Base-Emitter Saturation Voltage		V _{BE (sat)}	I _C = 18 A, I _B = 4.5 A	_	1.0	1.5	V
Transition Frequency		f _T	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz
Collector Output Capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	320	_	pF
Switching Time	Storage Time	t _{stg(1)}	I _{CP} = 8 A , I _{B1} (end) = 1 A	_	4	_	μs
	Fall Time	t _{f(1)}	$f_H = 32 \text{ kHz}$	_	0.15	_	
	Storage Time	t _{stg(2)}	I _{CP} = 7.5 A, I _{B1} (end) = 1 A	_	1.8	_	μs
	Fall Time	t _{f(2)}	f _H = 100 kHz	—	0.1	_	

Unit: mm

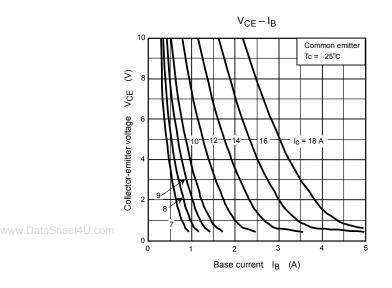
TOSHIBA

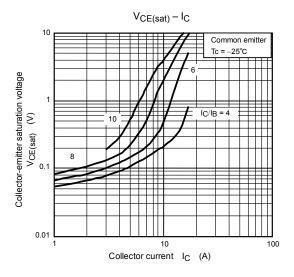


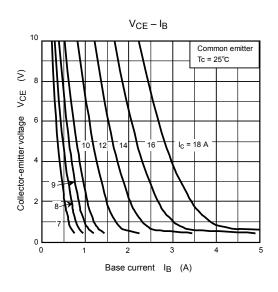


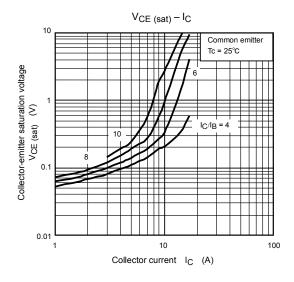


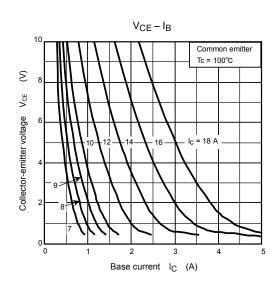
TOSHIBA

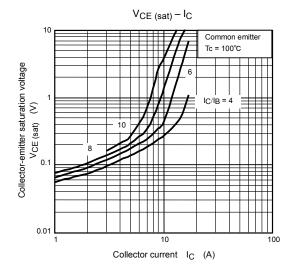


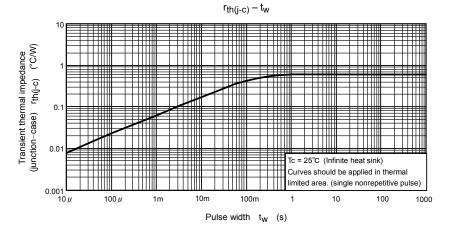






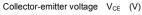


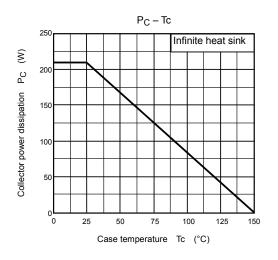




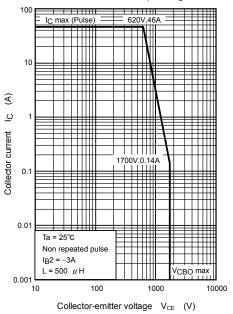
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Safe Operating Area 100 IC max (Pulse)* +1 ms*-100 μs* - 10 μs* max (Continuous) 100 m ₹ <u>ں</u> DC operation Collector current Tc = 25°C 0.1 *:Single nonrepetitive pulse Tc = 25°C Curves must be derated linearly with increase in VCEO max temperature. 0.01L 10 100 1000





Reverse Bias - Safe Operating Area



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